NSN 5961-01-098-9902

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass and metal
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
1.0 forward voltage, average
Current Rating Per Characteristic:
15.00 microamperes forward current, average peak
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0